

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of: Anthony *et al.*

Docket: TI-24953

Serial No.: 09/116,138

Examiner: B. Souw

Filed: 07/15/98

Art Unit: 2814

174/C  
7-25 00  
C Brown

High Permittivity Silicate Gate Dielectric




REPLY PURSUANT TO 37 C.F.R. § 1.111

June 7, 2000

Assistant Commissioner for Patents  
Washington, DC 20231

MAILING CERTIFICATE UNDER 37 C.F.R. § 1.8  
I hereby certify that this correspondence is being deposited with  
the United States Postal Service as first class mail in an envelope  
addressed to: Assistant Commissioner for Patents, Washington,  
DC 20231 on July 13, 2000.

  
David Denker Reg. No. 40,987

Examiner:

In response to the Office Action dated January 13, 2000, please amend the above-identified patent application as follows:

IN THE CLAIMS:

Please add Claims 41 - 45 as shown.

41. The method of Claim 1, where the metal silicate dielectric layer is a zirconium silicate dielectric layer.
42. The method of Claim 2, where the first metal is zirconium.
43. The method of Claim 16, where the first metal is zirconium.
44. The method of Claim 24, where the first metal is zirconium.
45. The method of Claim 28, where the metal silicate layer is a zirconium silicate layer.

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